



Status of ORION and E163

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On behalf of the ORION and E163 Collaborations:

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ORION Facility for Advanced Accelerator and Beam Physics Research

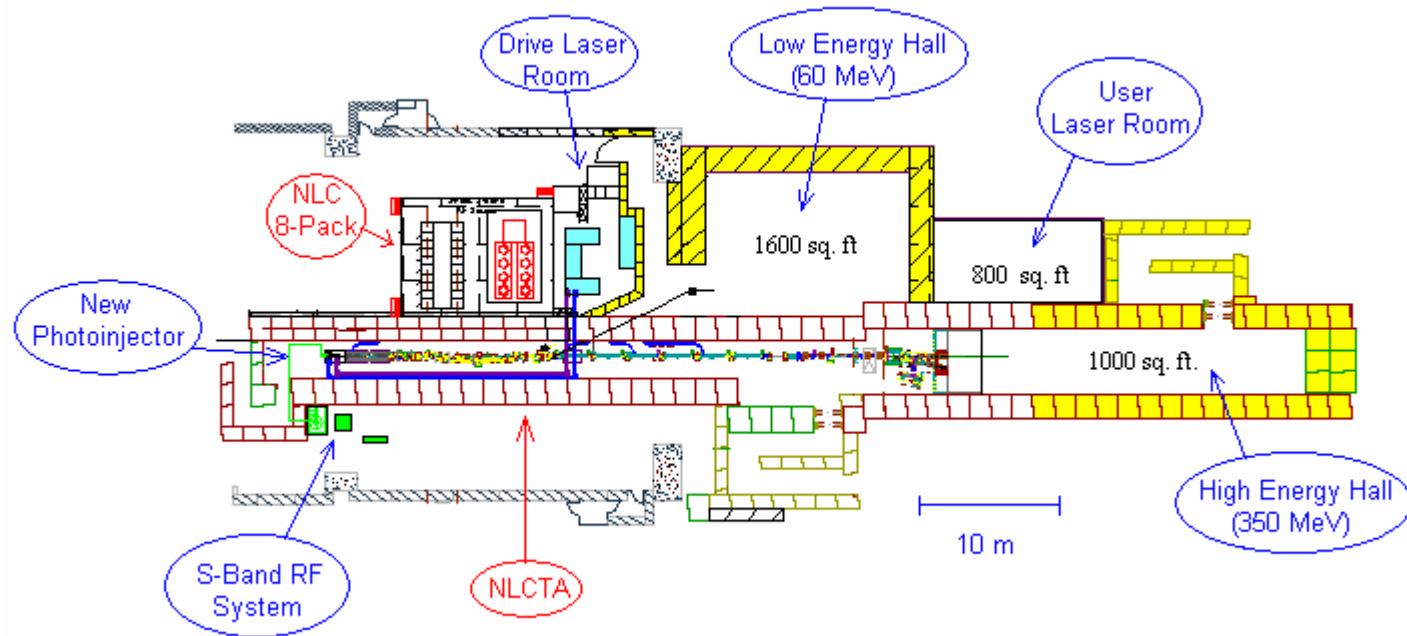


Location: Next Linear Collider Test Accelerator



ORION Facility at the NLCTA

Conceptual Layout



- Feedback received from potential users at the **2nd ORION Workshop**, Feb. 18-20, 2003.
- Attended by 85 enthusiastic participants from America, Europe, Asia!
- Working Groups on Beam-Plasma Physics, Laser Acceleration, Particle Sources, and Laboratory Astrophysics suggested many exciting new experiments!

Priority for the Plasma-Beam Physics Working Group: High Quality Acceleration with Narrow ΔE to be achieved through Drive and Witness Bunches

Critical Parameters:

Drive: < 2ps with > 1nC

Witness: 0.2 ps with .1 nC (light beam loading but narrow width limits ΔE)

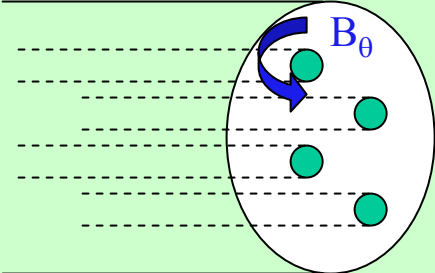
OR 0.4 ps with .3 nC (beam loading allowing for monoenergetic gain)

Questions:

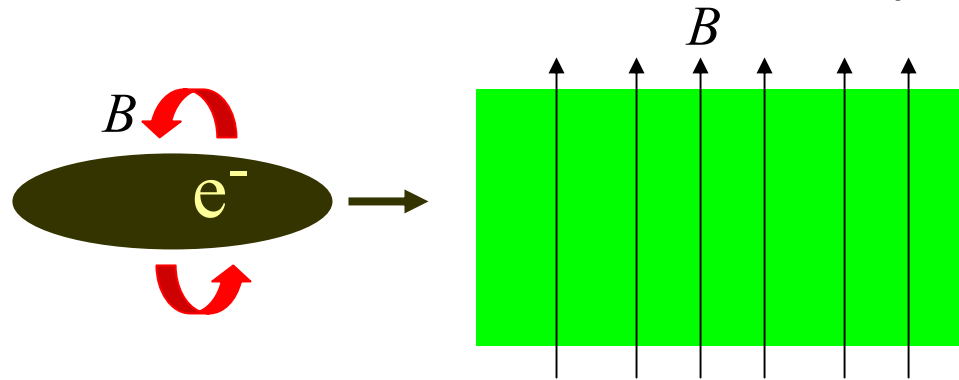
- * Given the beam optics what will the witness beam look like - σ_z , etc?
- * We can tolerate high emittance (x10). What charge and bunch length can we get?

New ORION Experiments:

From the Beam-Plasma Working Group, 2nd ORION Workshop

Experiment	Discussion
Basic Physics	
Heavy Beam Loading	Can give lower energy spread of accelerated particles (via wake flattening) and gives high efficiency .
Beam ionized Sources	Choose parameters such that the incoming beam can ionize the plasma source with tunnel ionization: <div style="text-align: center; border: 2px solid blue; padding: 10px; margin: 10px 0;"> $\left(\frac{Q}{nC}\right) > 1.6 \left(\frac{\sigma_r}{20\mu m}\right) \left(\frac{\sigma_z}{.2ps}\right)$ </div>
Astrophysics	<p>Weibel/Filamentation Experiment - Basic plasma physics, produces magnetic turbulence leading to synchrotron radiation. A possible model for GRBs. Needs as much charge and as long a pulse as possible & LARGE (~mm) spot sizes.</p> <p>Levels:</p> <ol style="list-style-type: none"> 1.) 60 MeV: Detect Filaments on screen 2.) 350 MeV: Detect Synch. Rad. 3.) 350 MeV + variable witness: Detect B field Lifetime <div style="text-align: right; margin-top: 20px;">  </div>

Cosmic Accelerators in Laboratory (Johnny Ng)

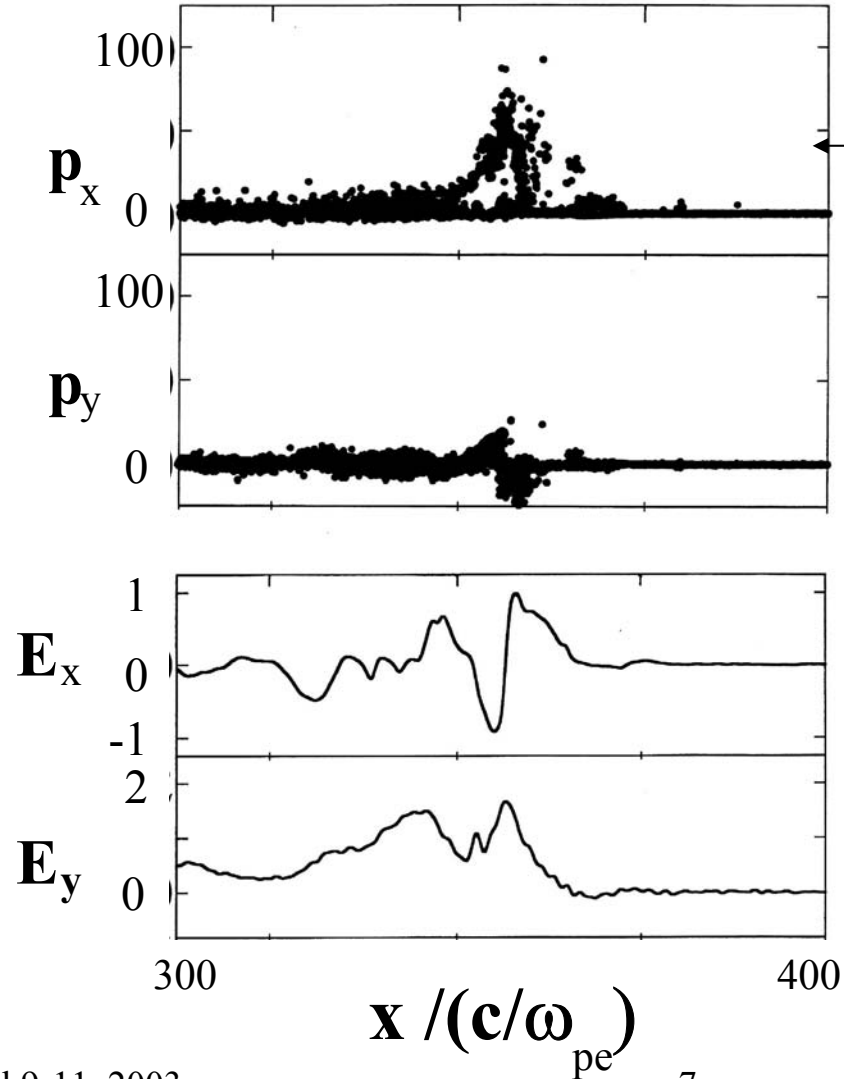
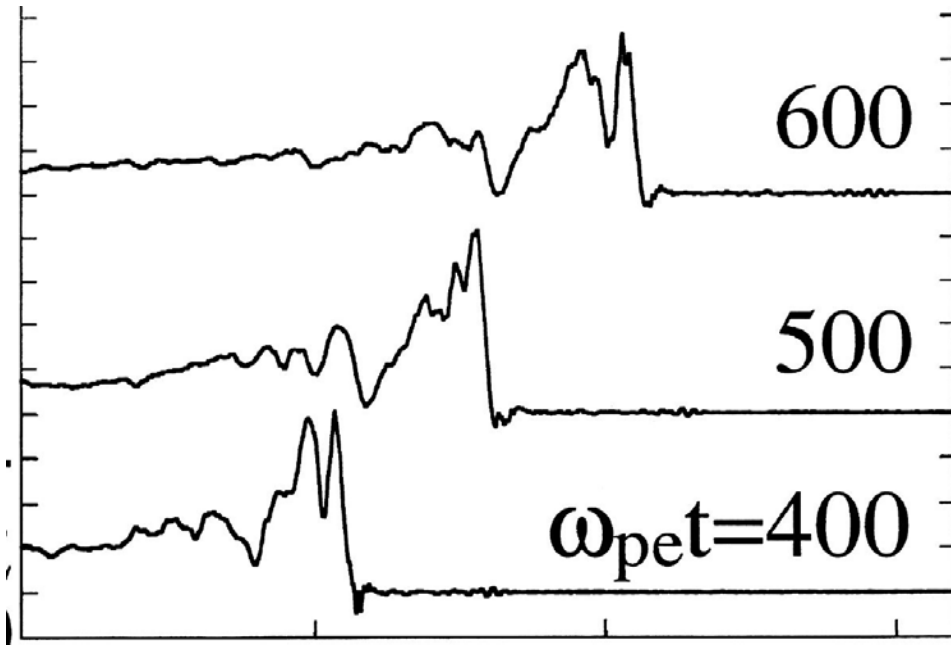


Relativistic charged beam
with strong magnetic fields

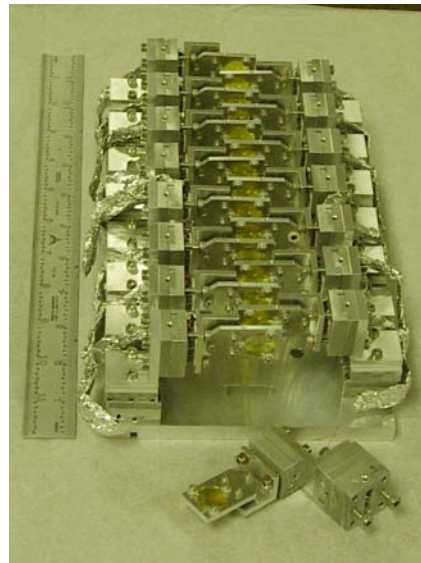
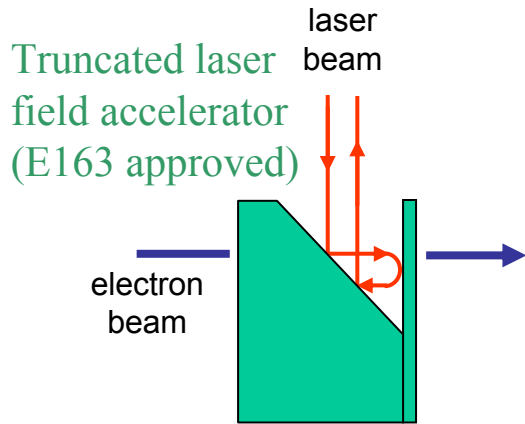
magnetized
ambient plasma

- Efficient way to produce Hybrid modes?
- Possible cosmic electron acceleration
- Relevant for ORION

**Nonlinear Alfvén Wave Dynamics:
Wave Steepening and Particle Acceleration
(Rick Sydora, U of Alberta)**

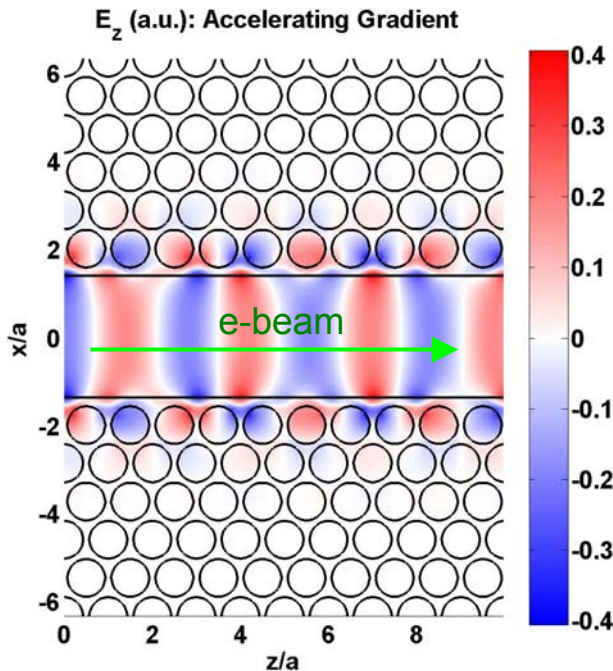
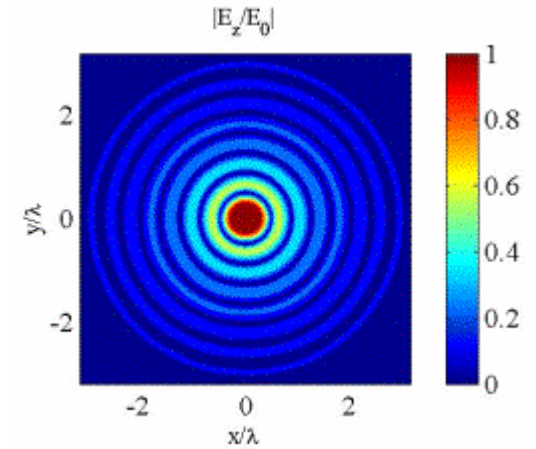


ORION Experiments from Laser Acceleration Working Group, 2nd ORION Workshop



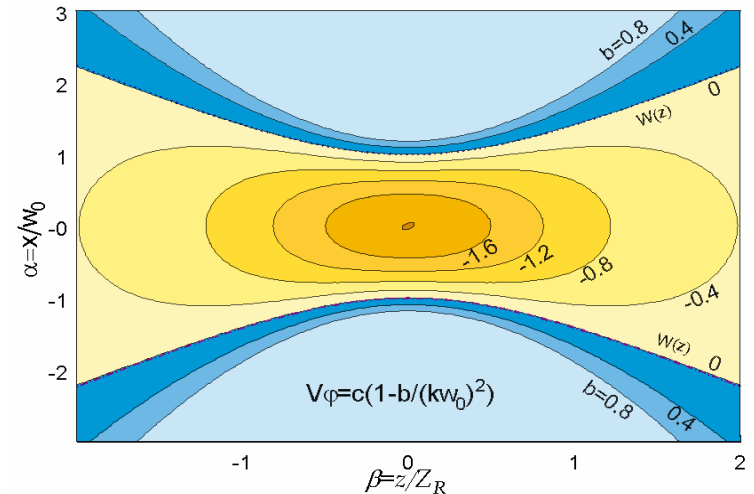
Multi-stage Laser Accelerator (NTHU, Taiwan)

Hollow Fiber Bragg Accelerator



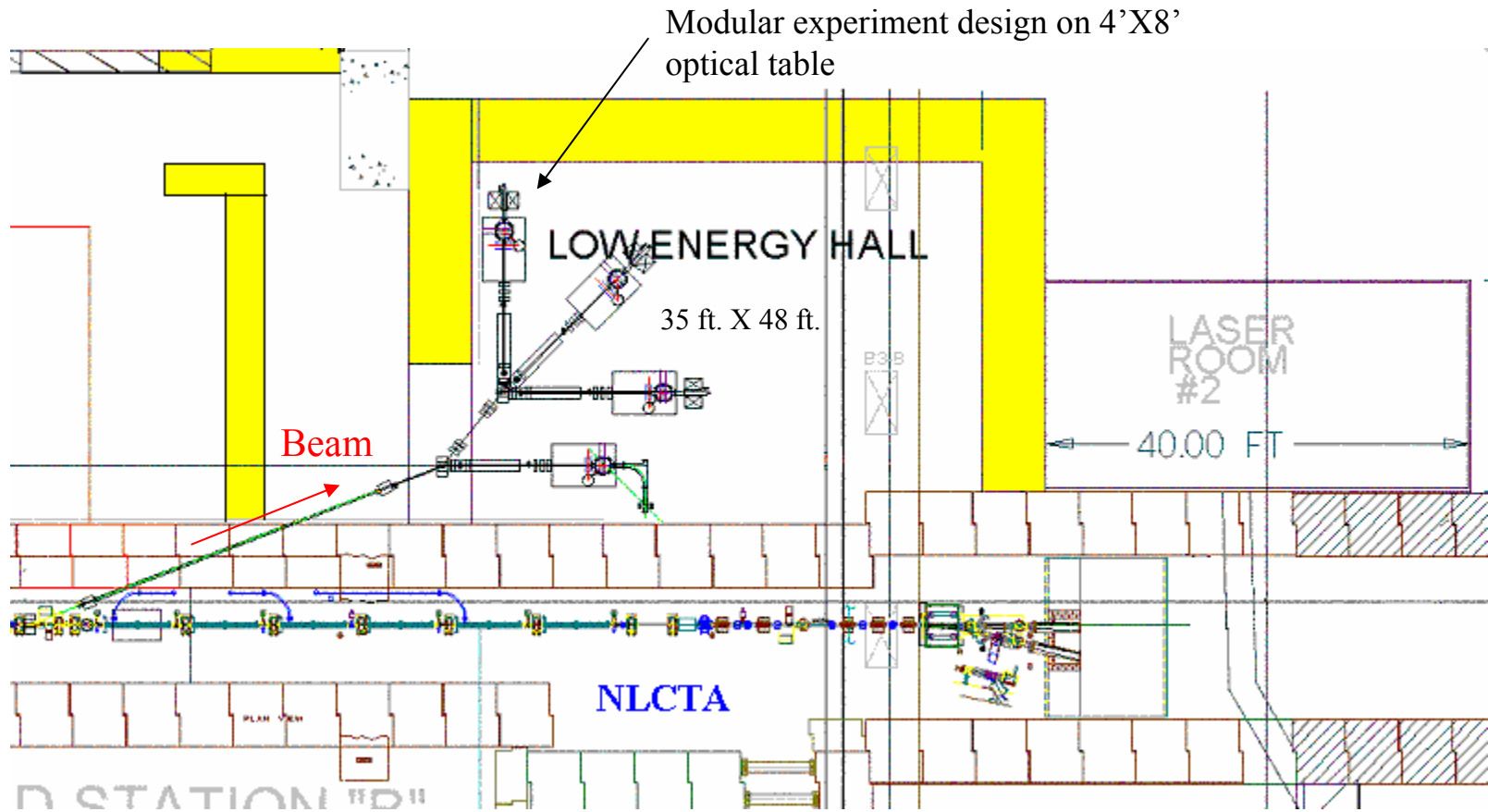
Photonic Crystal Laser Accelerator

Phase-Matched Vacuum Accelerator



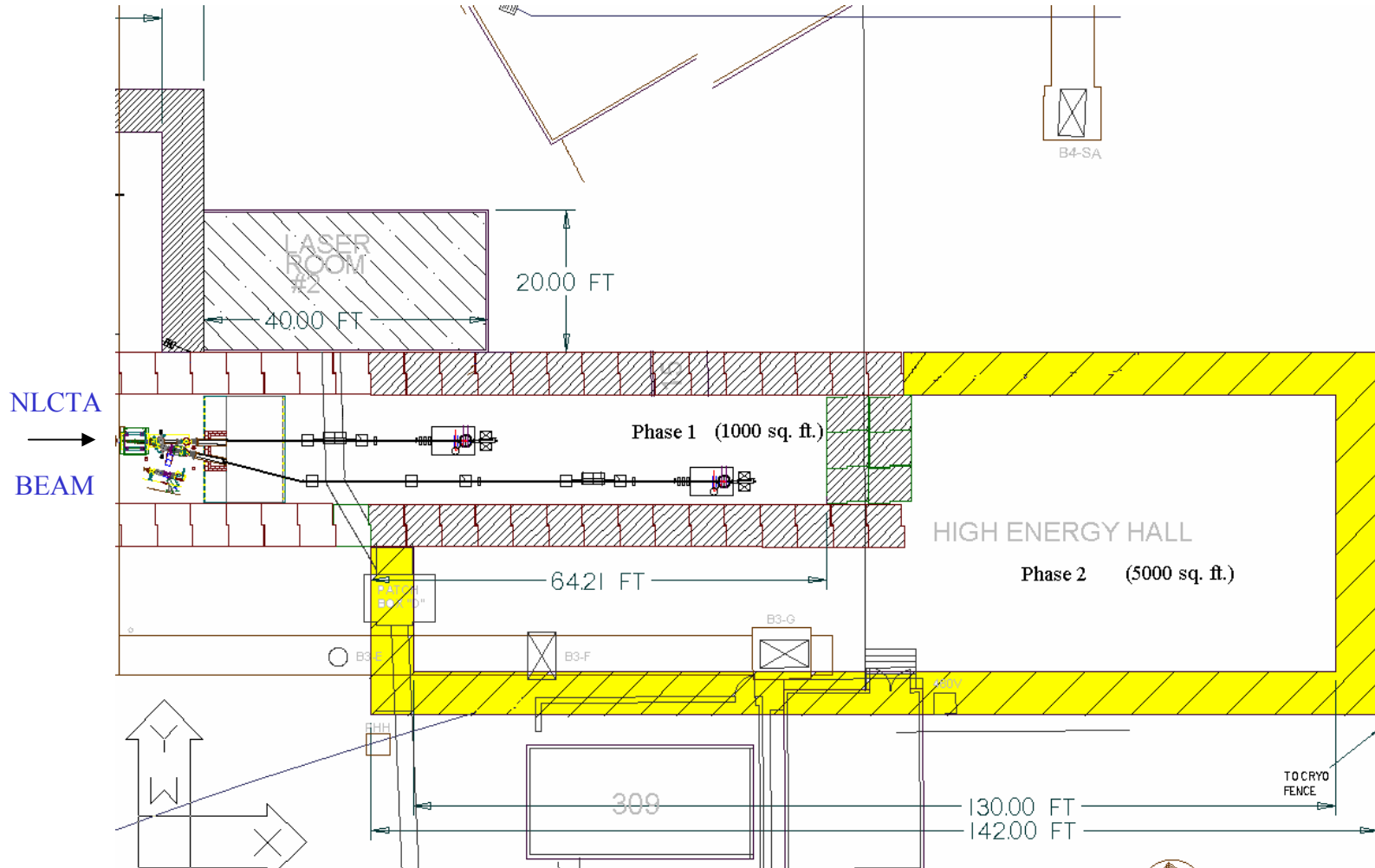


ORION Low Energy Hall: A Possible Beamline Layout



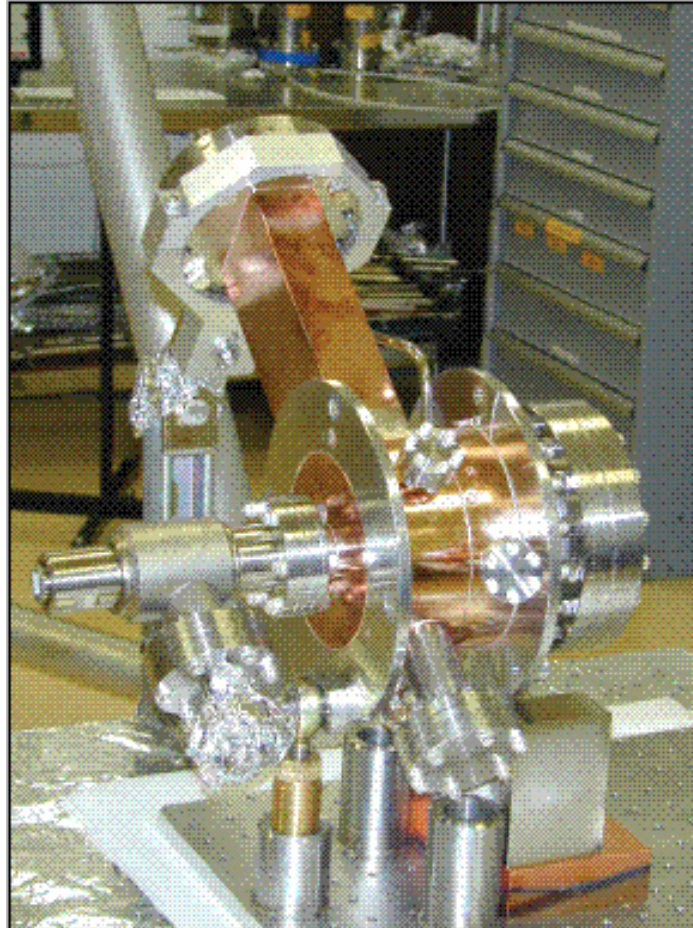


ORION High Energy Hall: Possible Beamline Layout





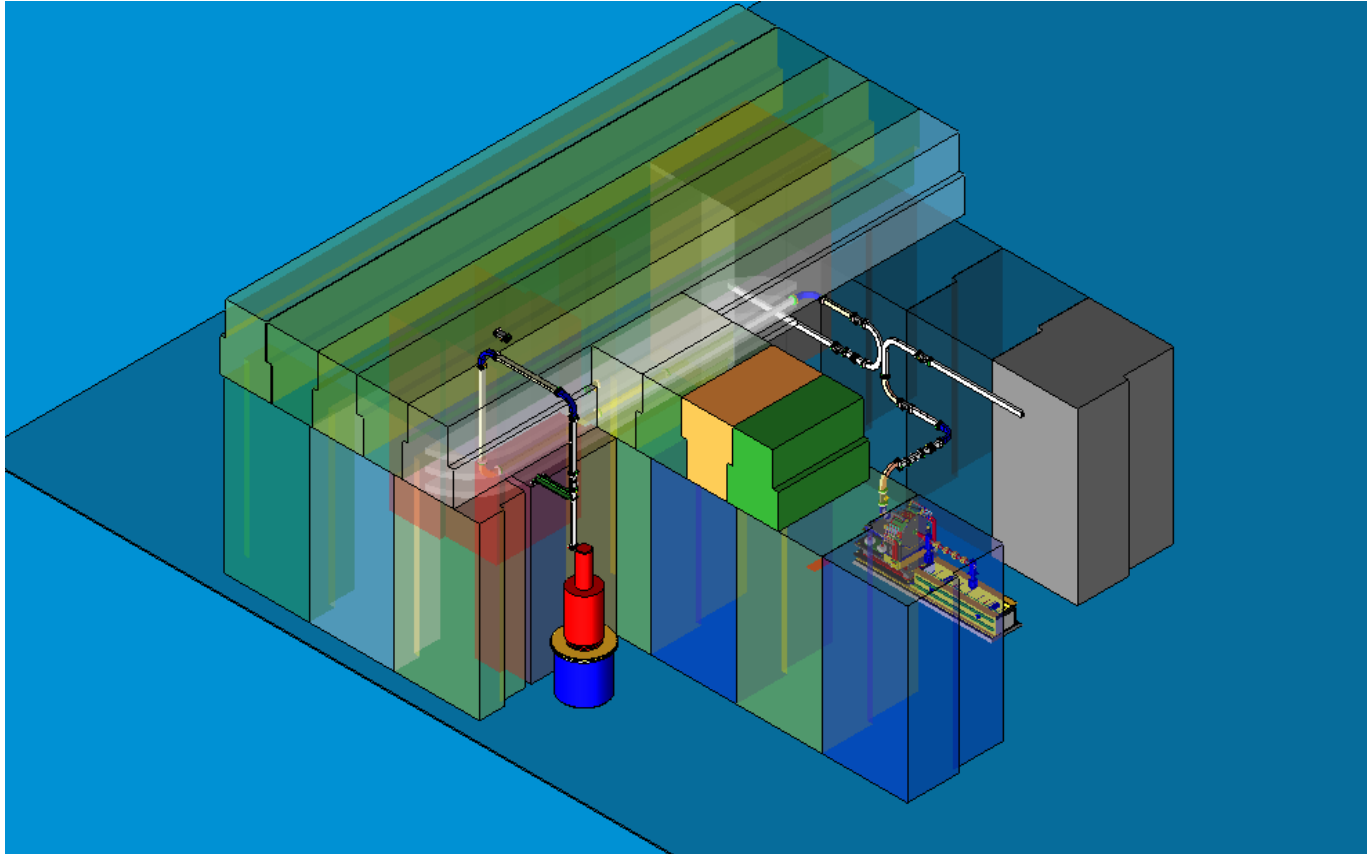
The S-Band RF Photoinjector for ORION/E163 is the same standard design as used at BNL, UCLA, etc.



RF gun constructed for E163 (Laser Accel.at NLCTA), brazed and will be high-power tested.



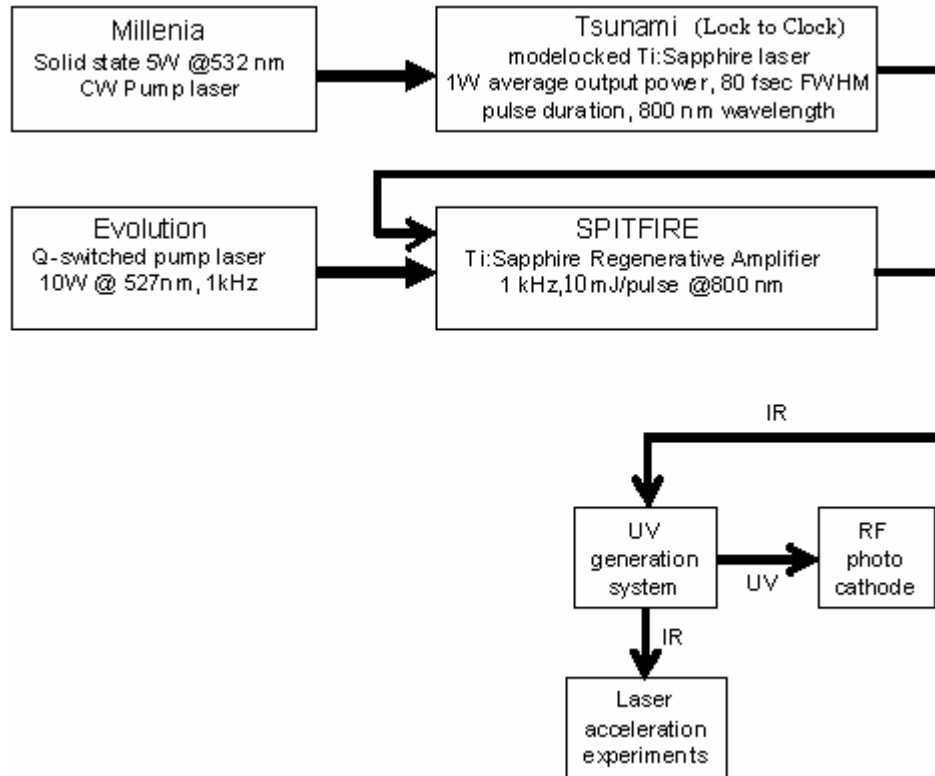
S-Band Klystron and WG Connection to RF Gun



SLAC has committed an S-band klystron, solid-state modulator and waveguide.



Drive Laser for Photoinjector



←Oscillator is existing SLAC equipment.

←2 mJ amplifier to be purchased as 2003 SLAC cap. equipment. (upgrade for ORION)

1 nC requires about 10 μ J on Mg cathode



E163: Laser Acceleration at the NLCTA

C. D. Barnes, E. R. Colby*, B. M. Cowan, R. J. Noble,
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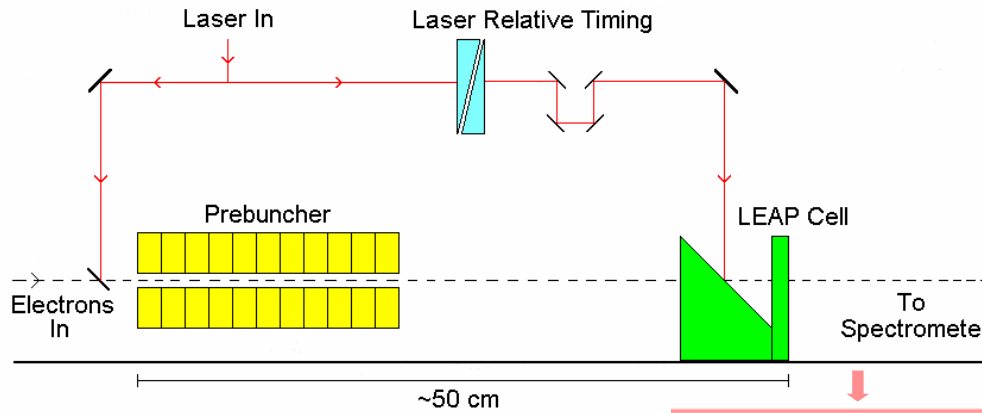
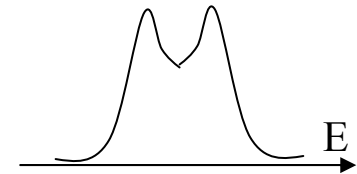
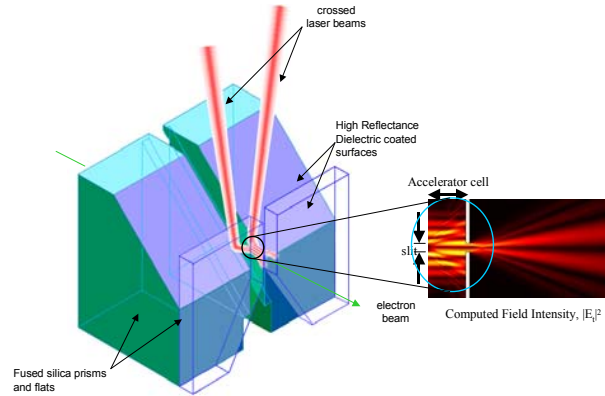
September 24, 2001

* Spokesman.



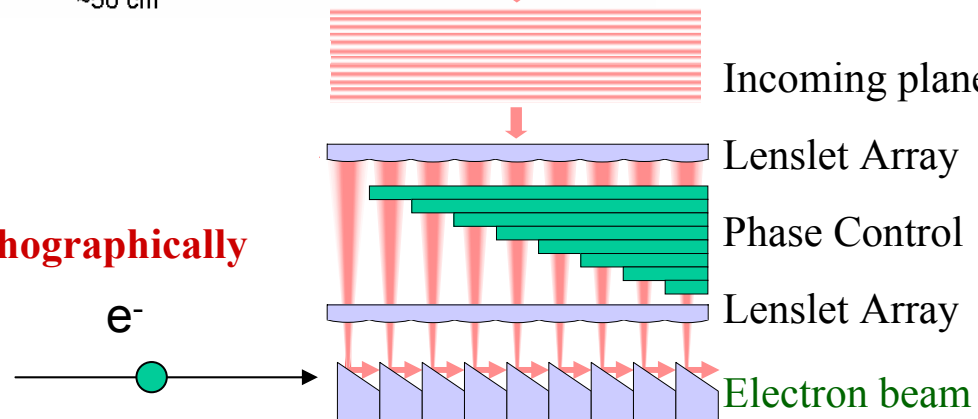
E163

Phase I. Characterize laser/electron energy exchange in vacuum



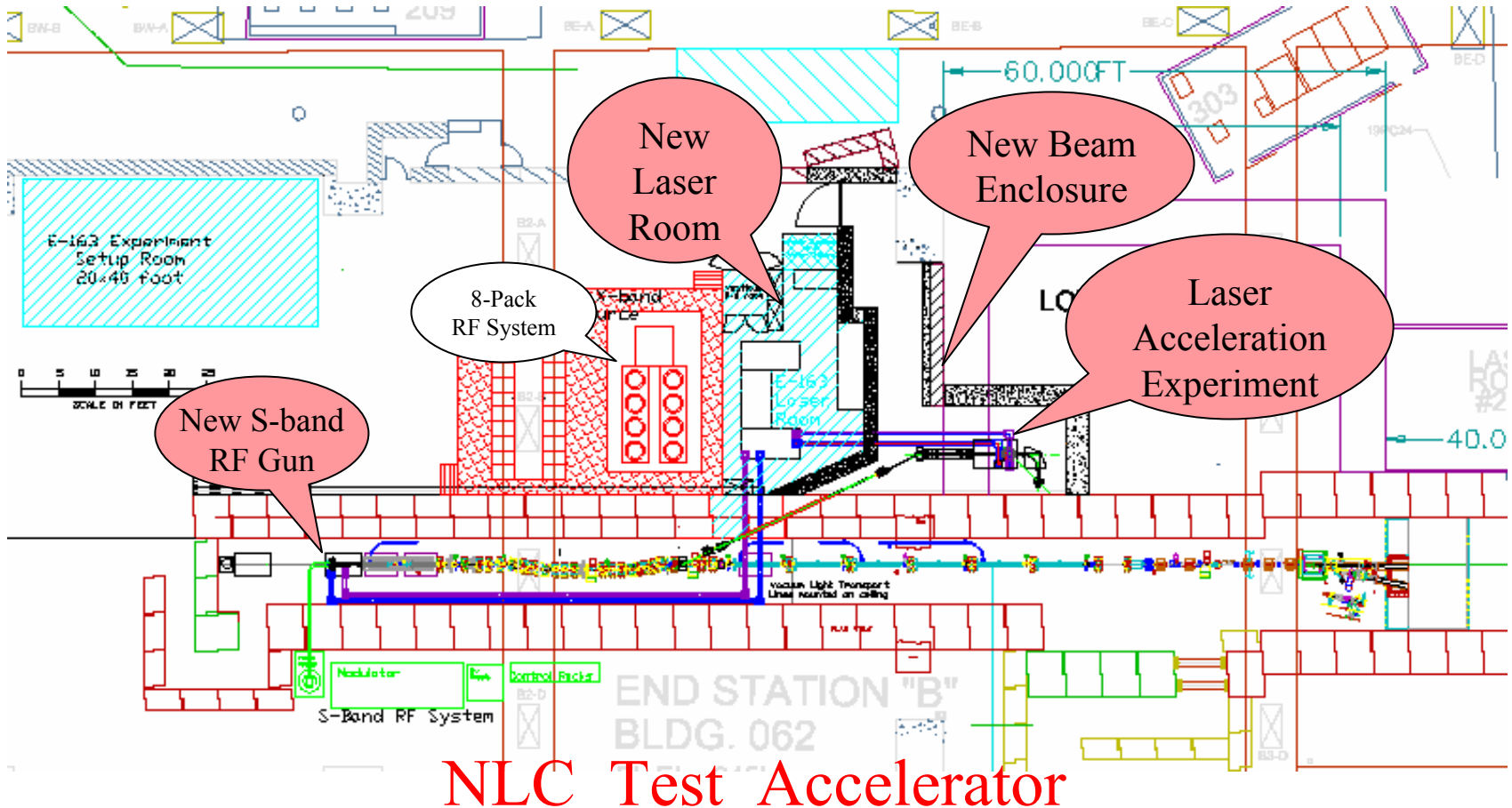
Phase II. Demonstrate optical bunching and acceleration

Phase III. Test multicell lithographically produced structures





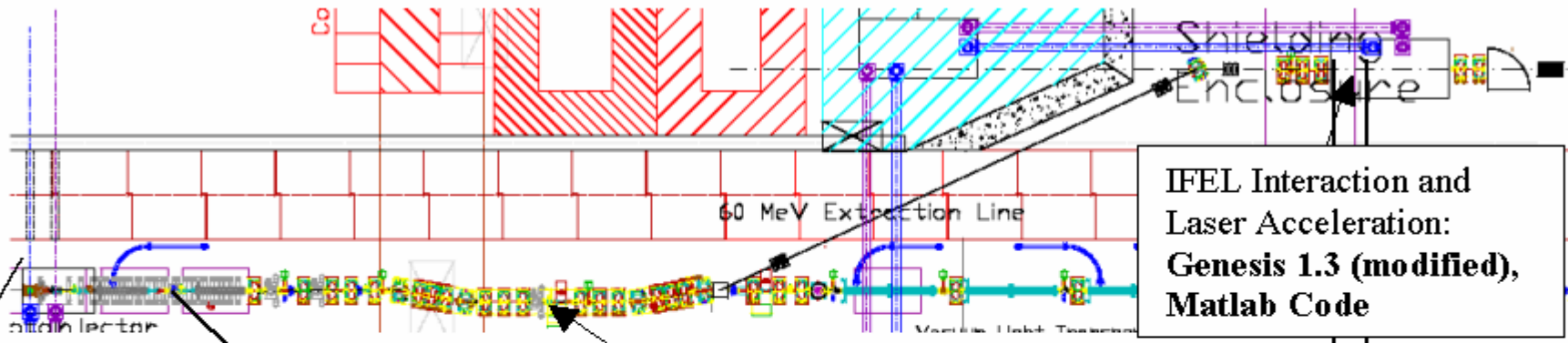
Laser Acceleration at the NLCTA





E163 End-to-End Simulations

Lesson for ORION is that one must understand the interplay between source beam behavior and the experimental signals to be measured.



Electron generation and acceleration to 32.5 MeV:
Parmela
(UCLA/SLAC)

Electron transport through 2nd accelerator, chicane, dogleg, energy scraper: **Elegant 14.6β2**, with accelerator structure and collimator wakefields from analytic treatment in the NLC-ZDR, and initial magnet settings from 2nd-Order Transport optimization.

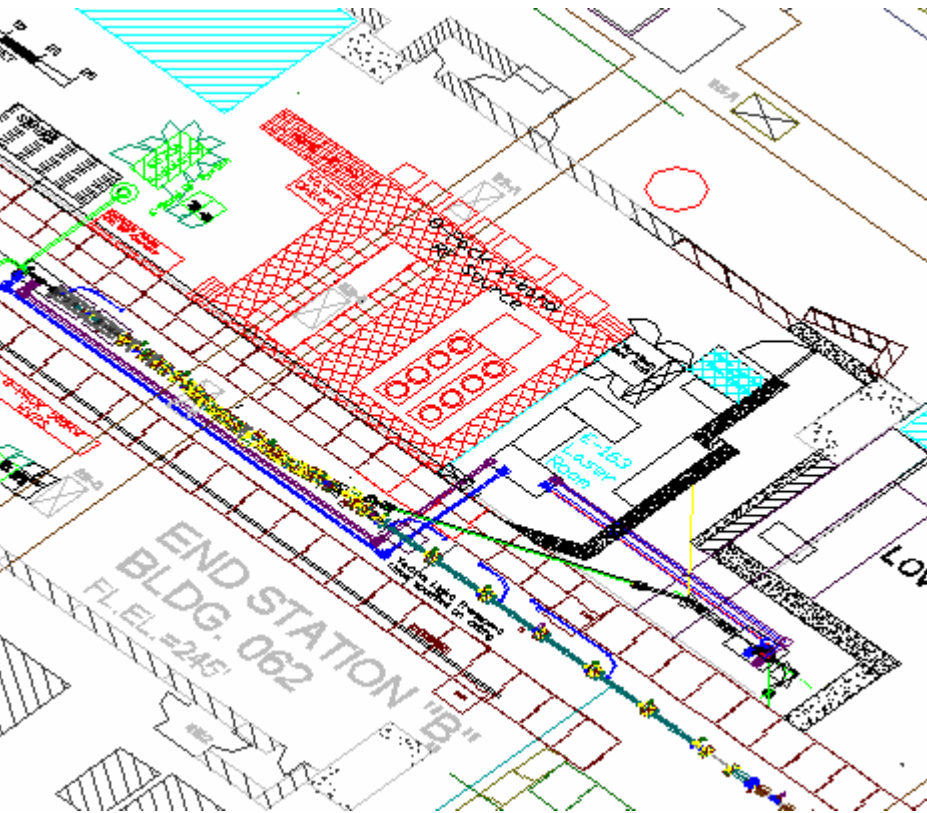
IFEL Interaction and Laser Acceleration:
Genesis 1.3 (modified), Matlab Code

Remainder of Transport:
Elegant 14.6β2

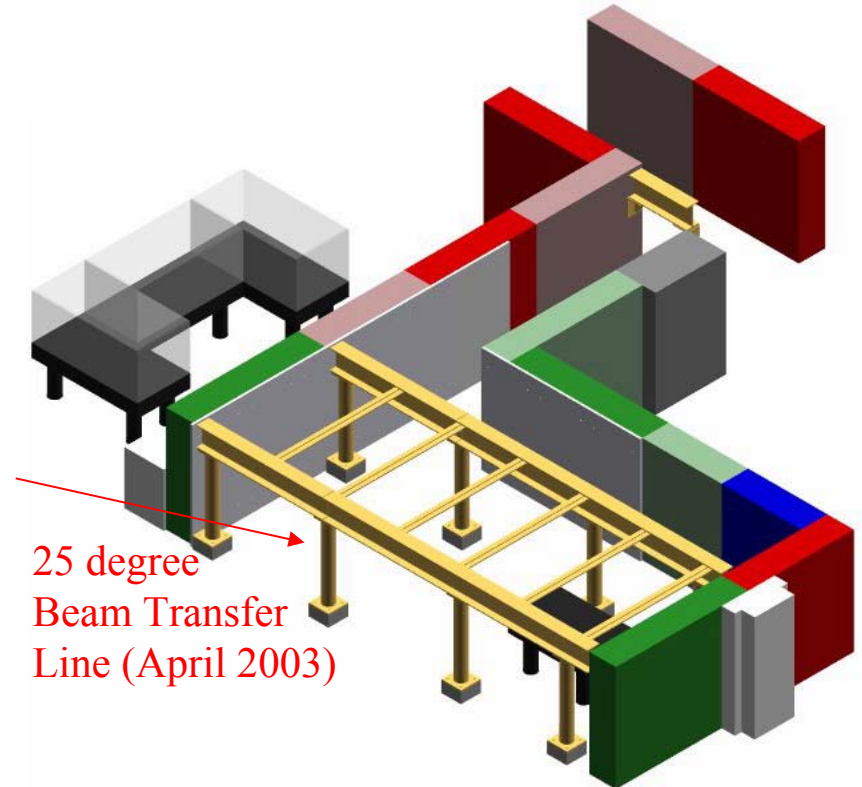


E163 Enclosure

Construction to start in May 2003

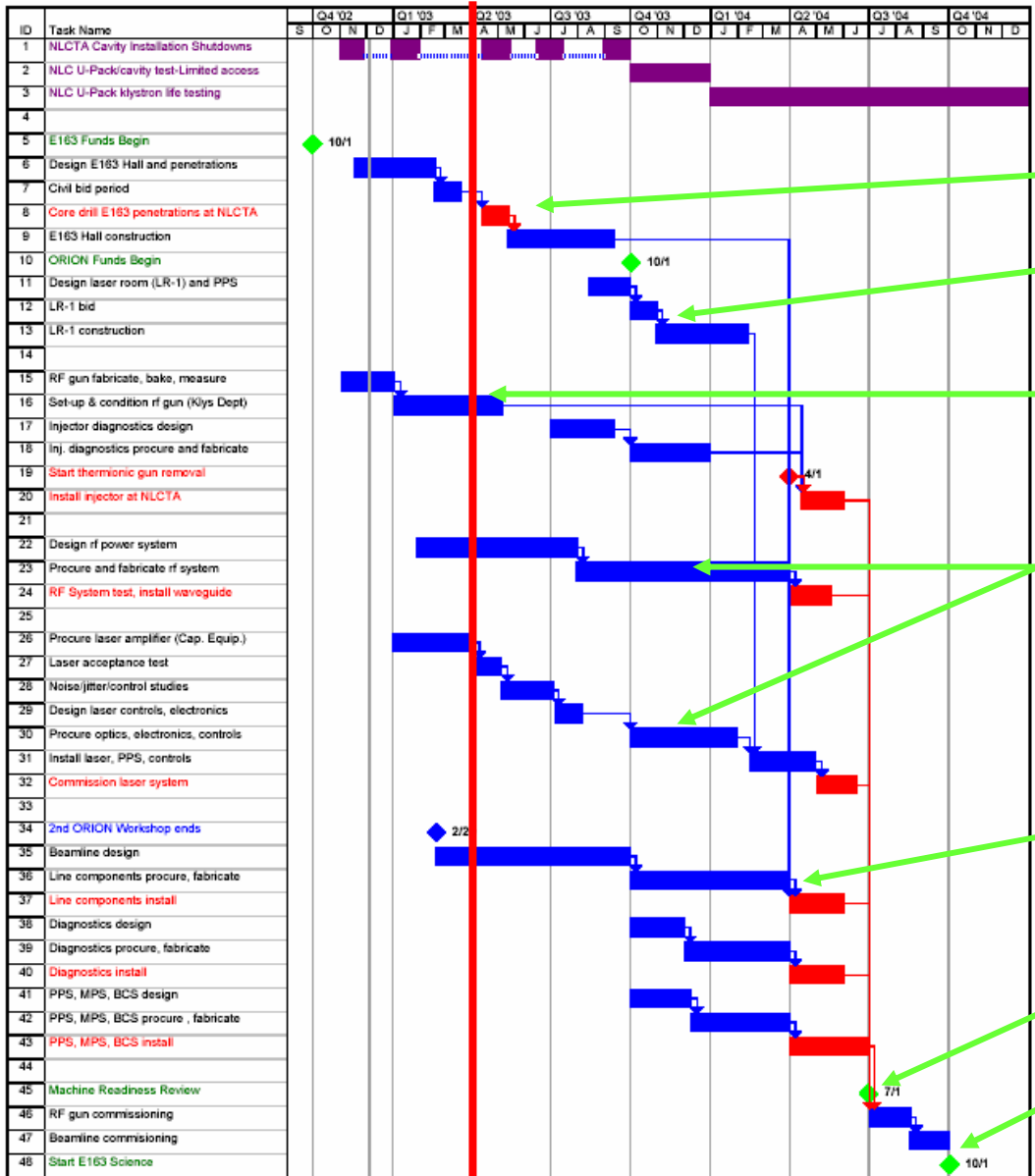


E163 Experimental area, original layout



25 degree
Beam Transfer
Line (April 2003)

E163 Shielded enclosure, as designed



Construct E163 Hall CY2003Q2

Laser Room 1 Construction
2003Q4 *

RF Gun Power Conditioning
2003Q2

Construct RF & Laser Systems
2003-04 *

Beamline Installation 2004Q2 *

Commission Beamline 2004Q3 *

Start E163 Physics 2004Q4 *

* Contingent on FY04 ORION
construction funds

Project: E163HighLevelSch-021114.mp
Date: Wed 12/4/02

Task		Rolled Up Task		Project Summary	
Split		Rolled Up Split		External Milestone	
Progress		Rolled Up Milestone		Deadline	
Milestone		Rolled Up Progress			
Summary		External Tasks			

Page 1



Summary of Major Steps to Date

- 1. E163 approved by SLAC Director in July 2002.**
- 2. Brazing of the E163/ORION rf gun, machined at UCLA, is complete.**
- 3. The early GTF solenoid coils, which have been recently replaced with new coils, are to be used for the gun focusing solenoid.**
- 4. Laser oscillator was procured with SLAC 2001 Cap. Equip. funds; 2 mJ amplifier for E163 is being purchased with 2003 Cap. Equip.; still require pump laser.**
- 5. The NLC prototype IGBT modulator has been reserved for use on the E163 rf system; SLAC will contribute an S-band 5045 klystron when needed.**
- 6. Penetrations at NLCTA for E163 beam line, rf waveguide and laser light approved and will be core drilled in mid-April.**
- 7. Surplus shielding blocks/girders identified at Stanford HEPL and on SLAC site which are adequate to build the E163 hall, as well as major parts of the ORION Low Energy Hall and the High Energy Hall in the future.**



The Future

During the next 5 years we anticipate performing path finding research to devise power-efficient lithographic structures with the ultimate goal of realizing an all-optical particle accelerator.

Thanks to the support of DOE and SLAC management, E163 is giving us a major head start on realizing ORION.

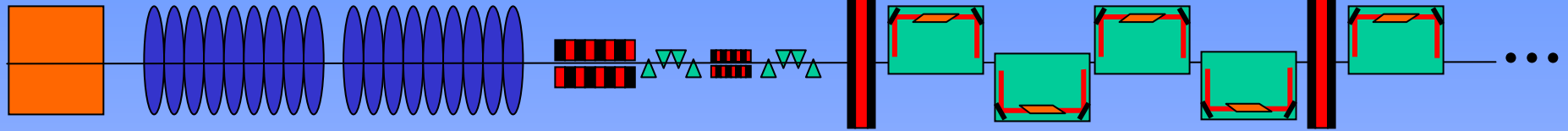
We are ready to go when funds arrive.



BACK-UP

SLIDES

Laser Linear Collider pre-Concept



CW Injector

Laser Accelerator

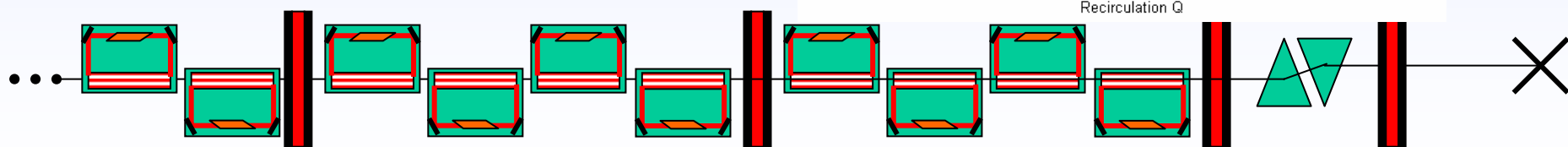
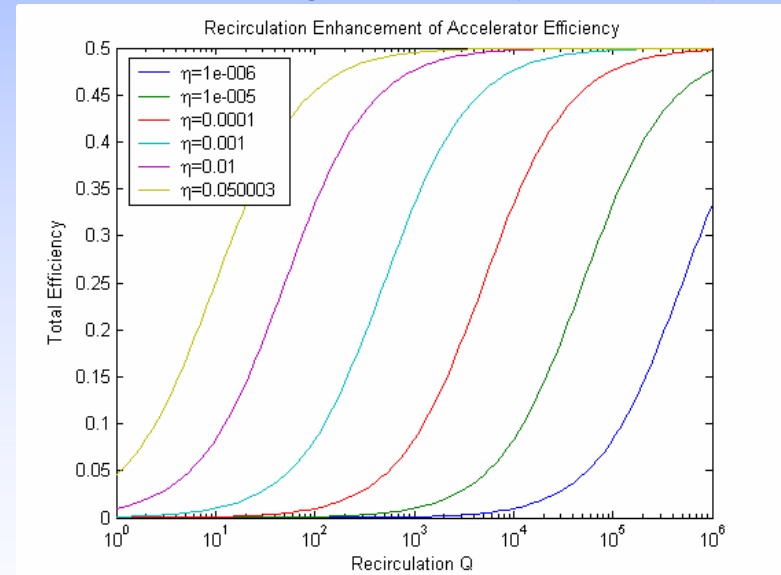
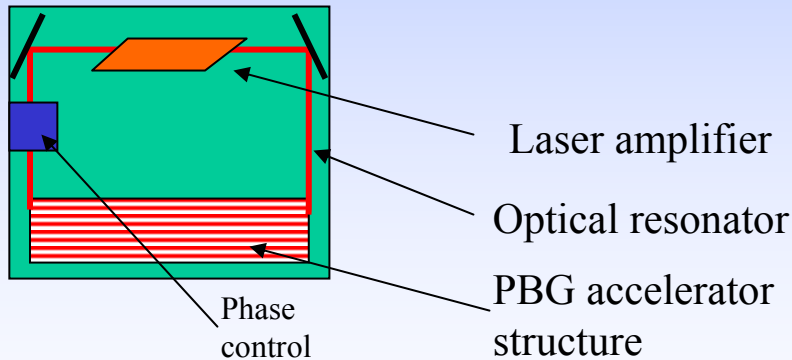
Warm rf gun Cold Preaccelerator Optical Buncher
 $433 \text{ MHz} \times 10^5 \text{ e}^-/\text{macropulse}$ ($600 \mu\text{pulse}/\text{macropulse}$)
 $\epsilon_N \sim 10^{-11} \text{ m}$ (but note $Q/\epsilon_N \sim 1 \mu\text{m}/\text{nC}$)

$\lambda = 1-2 \mu, G \sim 1 \text{ GeV}/\text{m}$

Photonic Band Gap Fiber structures
 embedded in optical resonant rings

Permanent Magnet Quads ($B' \sim 1 \text{ kT}/\text{m}$)

An Acceleration Unit



Optical Debuncher

Final Focus I.P.



The Promise of Laser Acceleration

Lasers produce unequalled energy densities and electric fields

Very short pulses permit higher surface electric fields without breakdown

Very short wavelengths (compared to microwaves) naturally lead to:

Sub-femtosecond electron bunches → sub-fs radiation pulses

Very short wavelengths require:

Very small emittance beams → radiation sources are truly point-like

Lasers development is strongly driven by industry

Lasers are a **\$4.8B/year market** (worldwide), with laser diodes accounting for 59%, DPSS lasers **\$0.22B/year**, and CO₂ lasers **\$0.57B/year** [1] (in contrast, the domestic microwave power tube market is **\$0.35B/year**, of which power klystrons are just **\$0.06B/year**[2]).

Peak Powers of TW, average powers of kW are readily available from *commercial products*

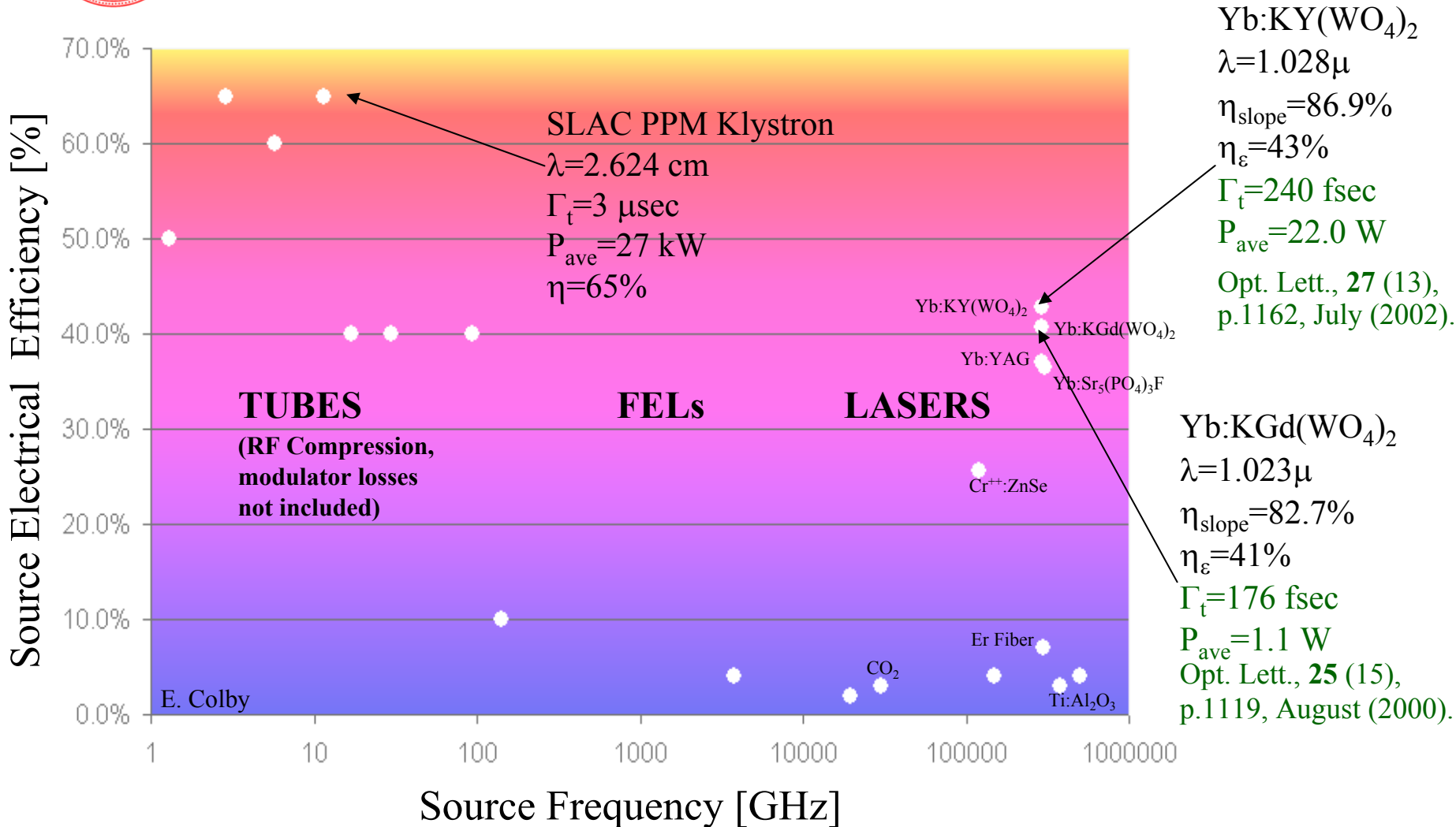
The market's needs and accelerator needs **overlap substantially: Cost, reliability, shot-to-shot energy jitter, coherence, mode quality are common to both.**

[1] K. Kincade, "Review and Forecast of the Laser Markets", Laser Focus World, p. 73, January, (2003).

[2] "Report of Department of Defense Advisory Group on Electron Devices: Special Technology Area Review on Vacuum Electronics Technology for RF Applications", p. 68, December, (2000).



Electrical Efficiency of Lasers





Recent Progress in Optical Materials

High Damage Threshold Materials

- Optical-quality CVD diamond
- ZnSe

High Thermal Stability Materials

- Ultra-high thermal stability optical materials (Photonics Jan 2003, p.158)
(factor of 2 better than Zerodur)
- +ve/-ve material sandwich that has $\beta=(1/n)*dn/dT+\alpha\sim 0$ (same article as above)

Lithographically Treatable Materials

- Silicon ($\lambda > 1500\text{nm}$) Silica
- Optical ceramics Nd:YAG



High average power ultra-fast lasers

Existing widespread commercial ultra-fast laser systems: Ti:sapphire

Poor optical efficiency → poor wall-plug efficiency

Low saturation → low power systems (typically few Watts per laser)

Large scale multi-component systems that require water cooling

High costs systems (~100 k\$/laser of ~1 Watt avg. power)

Requirements for future ultra-fast lasers for particle accelerators

1. Power scalability to hundreds for Watts of average power per laser
2. Wall-plug efficiency > 20%
3. Mass producible, reliable and low-cost
4. Ultra low optical phase noise

Driving Applications

Industry and Basic Research

Materials Processing, ultrafast laser machining, via drilling, medical therapeutics, entertainment, image recording, remote sensing

Defense

Coherent laser radar, remote wind sensing, remote sensing of “smart dust”, trans-canopy ranging, and stand-off coherent laser inspection of laminated-composite aircraft components



Candidate laser host materials for ultra-fast high-power lasers

Monocrystalline materials

→ Materials with low quantum defect, excellent slope efficiency, and good thermal conductivity

Yb:KGd(WO₄)₂ slope efficiency 82.7% [Opt. Lett., 22 (17) p.1317, Sept. (1997)]
limiting electrical efficiency of 41% (assuming 50% efficient pump diode)

Yb:KY(WO₄)₂ slope efficiency 86.9% [Opt. Lett., 22 (17) p.1317, Sept. (1997)]
limiting electrical efficiency of 43% (assuming 50% efficient pump diode)

Polycrystalline materials

Nd:YAG	}	• Better homogeneity of dopant
Nd: Y ₂ O ₃		• Lower fabrication cost
Cr ²⁺ :ZnSe		• Possible tailoring of dn/dT
Nd:Y ₃ Sc _x Al _(5-x) O ₁₂		• Single crystal growth still possible

Commercially Available High Efficiency Laser Diode Bars



Preliminary Data Sheet | NL-SAG



**3900 W, $\eta_e=40\%$,
 $\lambda=792-812$ nm**

300W, $\eta_e=50\%$, $\lambda=780-1000$ nm

Part Number: ARR04P3900

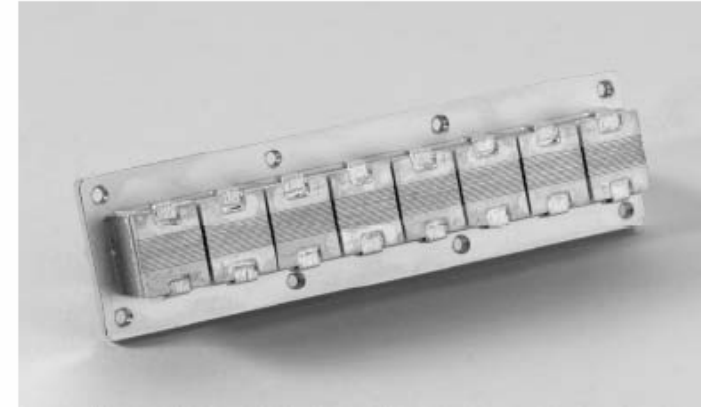
High Power Stacks

nLight Photonics' high power stacked bar module provides state-of-the-art power levels in a compact package. Starting with high power diode 1 cm bars, multiple modules are stacked to provide extremely high output power. These modules are water cooled to maximize output power without sacrificing the lifetime of the diode.



Z PACKAGE

- Packaged 112 Bar Laser Diode Array
- Other Powers Are Also Available
- Available Wavelengths 785-1064nm



Optical

Center Wavelength (Range)	780-1000nm
CW Output Power	300W (6 plates)
Center Wavelength Tolerance	± 3.0 nm
Array Length	1cm

Electrical

Total Conversion Efficiency	50%
Threshold Current	10A
Operating Current	60A
Operating Voltage	< 12V
Series Resistance	0.04 Ω

Thermal

Thermal Resistance	0.35 $^{\circ}$ C/W
Operating Temperature	10 $^{\circ}$ C to 40 $^{\circ}$ C
Fluid Flow Rate	300 ml/min/plate
Inlet to Outlet pressure drop	30 psi
Deionized Water Resistivity	.5 - 2Mohm-cm
Filter	< 20 μ m

OPTICAL CHARACTERISTICS

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
QCW Peak Power Output	60A, 150 psec, 1kHz	3900	---	---	W
Operating Current	3900W at 25 $^{\circ}$ C Heat Sink	---	55	60	A
Threshold Current	25 $^{\circ}$ C Heat Sink	---	13	16	A
Slope Efficiency	25 $^{\circ}$ C Heat Sink	106.4	123.2	---	W/A
Efficiency	3900W at 25 $^{\circ}$ C Heat Sink	35	40	---	%
Number of Emitters	---	---	72 x 112	---	
Emitter Size	---	---	90 x 1	---	μ m
Emitter Pitch	---	---	133.3	---	μ m
Center Wavelength	3900W at 25 $^{\circ}$ C Heat Sink	792	808	812	nm
Wavelength Tolerance	3900W at 25 $^{\circ}$ C Heat Sink	± 1	± 3	± 4	nm
Spectral Width	3900W at 25 $^{\circ}$ C Heat Sink	---	4.0	5.0	nm
Wavelength Shift	---	0.23	0.25	0.27	nm/ $^{\circ}$ C
Beam Divergence FWHM ⁽¹⁾	---	---	40x10	42x12	$^{\circ}$ x $^{\circ}$
Polarization	---	---	TE	---	---
Degradation Rate ⁽²⁾	25 $^{\circ}$ C Heat Sink	---	5	---	%/G shots

ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Built-in Voltage	25 $^{\circ}$ C Heat Sink	---	179.2	190.4	V
Series Resistance	25 $^{\circ}$ C Heat Sink	---	0.896	1.344	ohms
Operating Voltage	25 $^{\circ}$ C Heat Sink, 3900W	---	224	257.6	V

U.S. Patent Numbers: 5,734,672 5,913,108

NOTES

- (1) Lower beam divergence is also available.
- (2) Typical degradation rates are 5% in the first 10 million shots and 5% per billion shots thereafter.



Laser **phase-locking** to a microwave reference with great stability has been demonstrated.

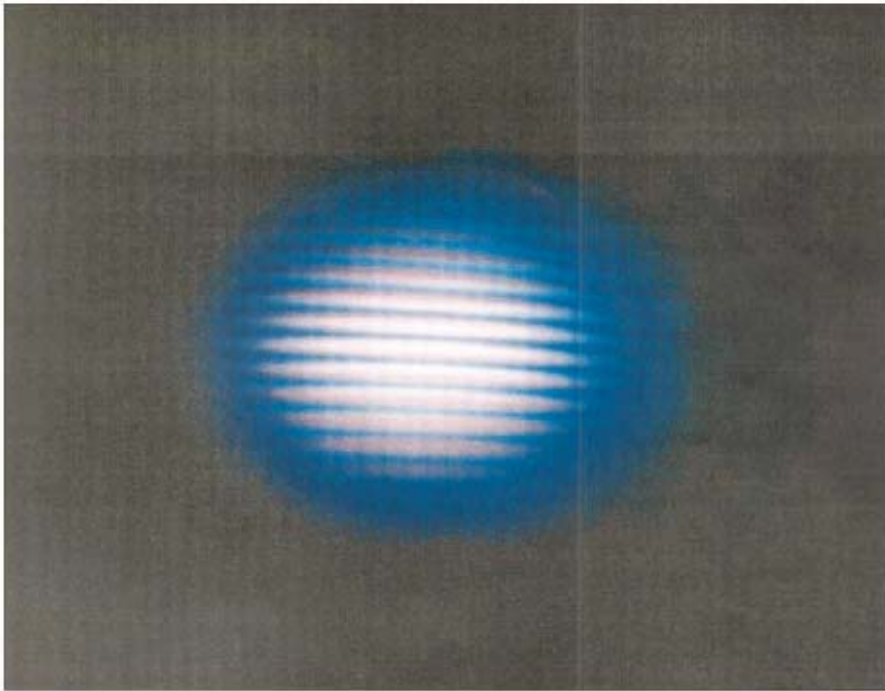


Fig. 2. White-light fringes resulting from the interference of the two continua generated by the two phase-locked IR laser pulses when the relative delay is properly adjusted to zero.

Interference fringes of carrier phase-locked white light continua generated from a Ti:Sapphire laser.

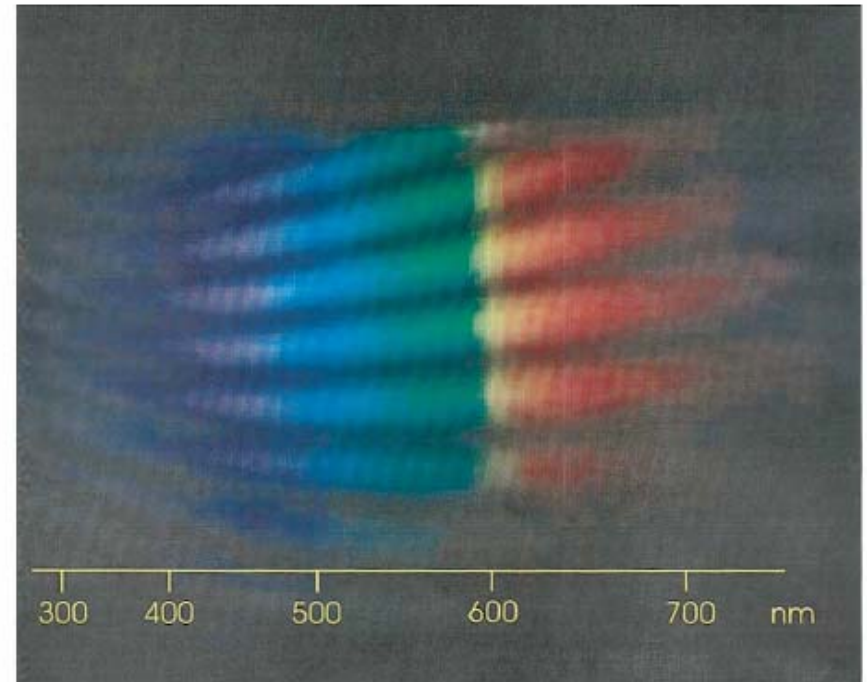
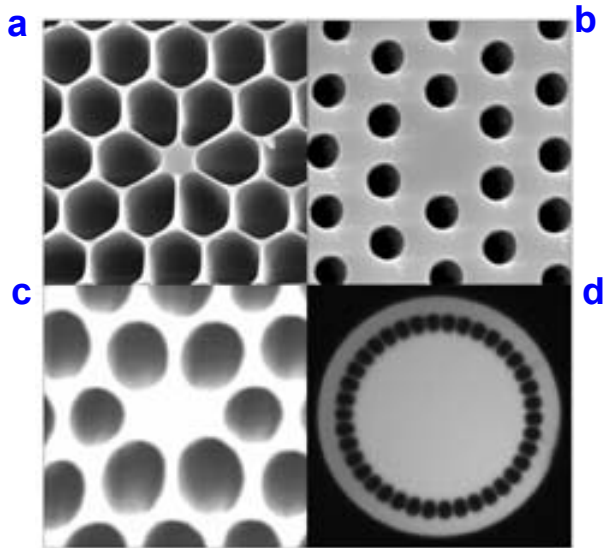


Fig. 3. Spectrally dispersed white-light fringes. Clear and well-defined fringes indicate that a stable phase relationship is conserved across all the generated visible spectrum.

M. Bellini, T Hansch, *Optics Letters*, **25** (14), p.1049, (2000).



Photonics Trend: Custom Optical Media



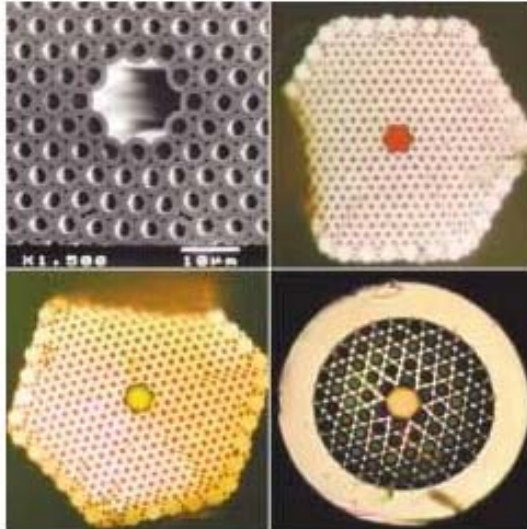
PCF structures vary according to application: (a) highly nonlinear fiber; (b) endlessly single-mode fiber; (c) polarization maintaining fiber; (d) high NA fiber. From René Engel Kristiansen (Crystal Fibre A/S), "Guiding Light with Holey Fibers," *OE Magazine* June 2002, 25.

- Photonic Crystals allow for tailoring optical properties to specific applications:
 - Nonlinearity: Spectroscopy, wavelength conversion in telecom
 - Dispersion: Telecom signal processing
 - Large mode area: High power applications such as lithography and materials processing
- Custom optics require manufacturing techniques that can meet tight tolerances

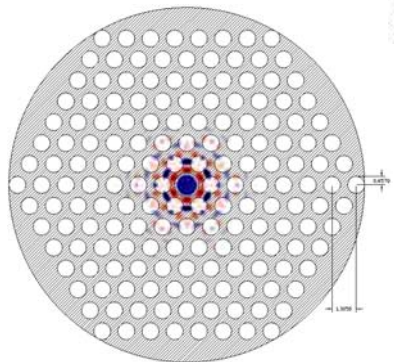
Laser Accelerator Microstructures

Photonic waveguides are the subject of intensive research, and can be designed to propagate only the accelerating mode.

P. Russell, "Holey fiber concept spawns optical-fiber renaissance", *Laser Focus World*, Sept. 2002, p. 77-82.

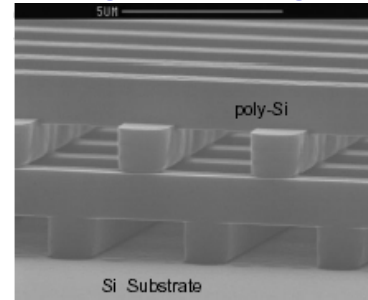


A scanning electron micrograph of guiding hollow-core PCF with core diameter 15 μm (top left); guided colors are seen in the core when white light was launched into two fibers of slightly different sizes (top right and bottom left); practical recent hollow-core PCF has solid outer cladding (bottom right).

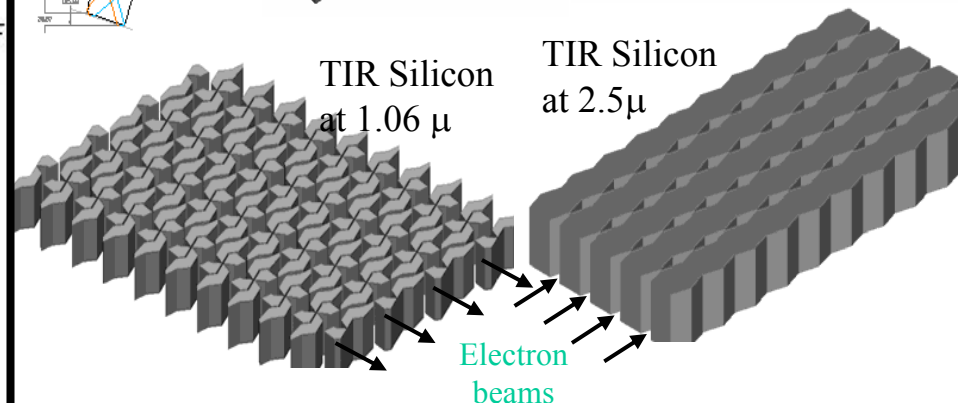
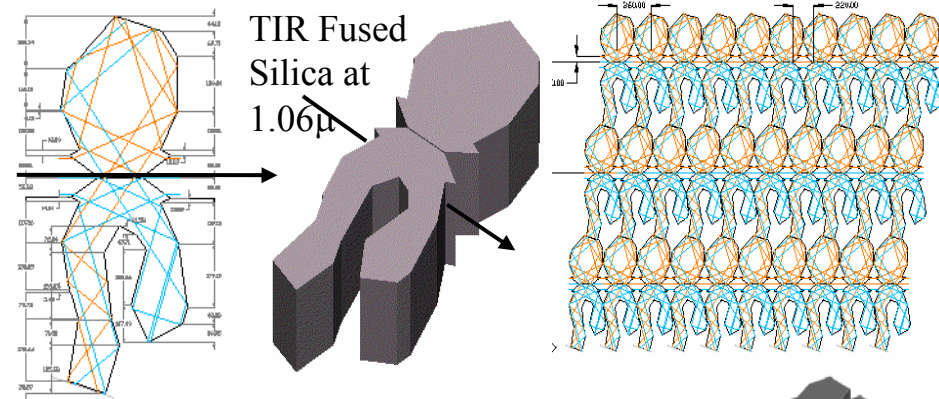


X. Lin, *Phys. Rev. ST-AB*, **4**, 051301, (2001).

Semiconductor lithography is capable of highly accurate, complex structure production in materials with good damage resistance and at low cost.



S. Y. Lin *et. al.*, *Nature* **394**, 251 (1998)

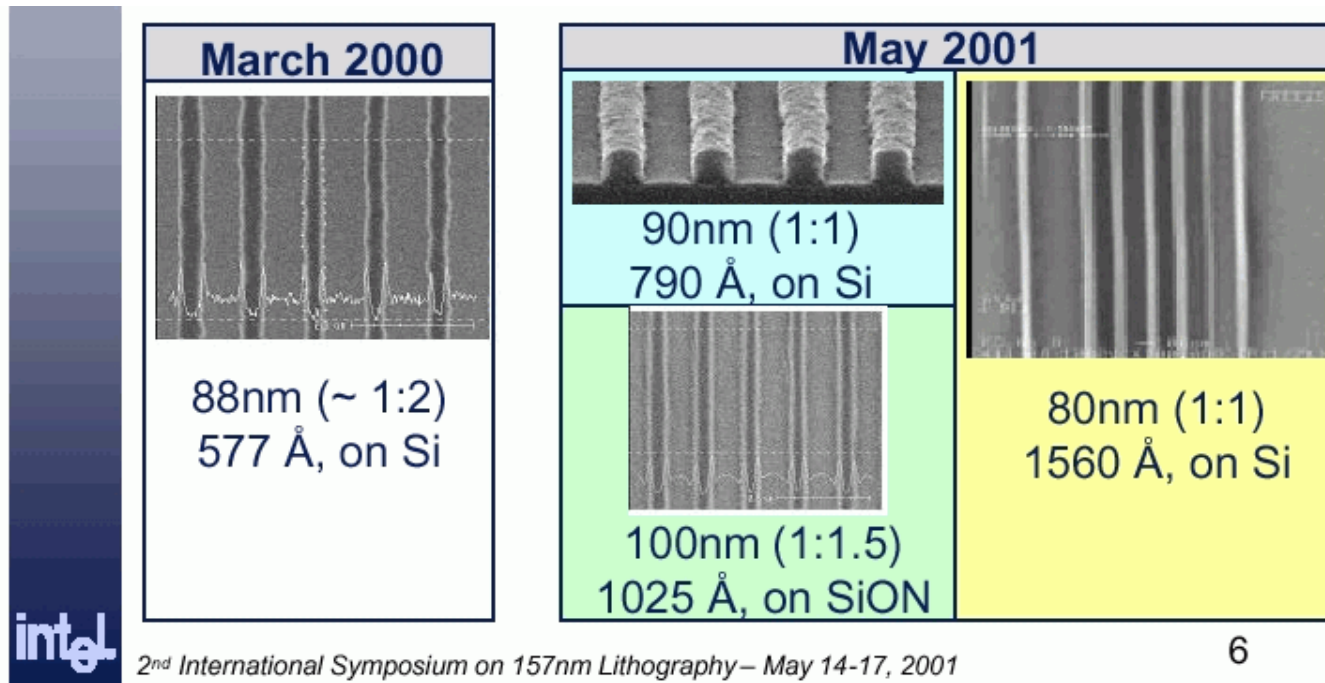




Fabrication Trend: Small Feature Size

The integrated circuit industry drives development of ever-smaller feature size capability and tolerance

- DUV, X-ray and e-beam lithography
- High-aspect-ratio etching using high-density plasma systems
- Critical Feature size control \rightarrow 0.5 nm ($\lambda/200$) RMS by 2010 ('01 ITRS)



2nd International Symposium on 157nm Lithography – May 14-17, 2001

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Demonstration of recent progress in lithography

Semiconductor and Advanced Opto-electronics Material Capabilities at Stanford



- Infrastructure: 10,500-square-foot class 100 cleanroom
- Research includes a wide range of disciplines and processes
 - Used for optics, MEMS, biology, chemistry, as well as traditional electronics
 - Equipment available for chemical vapor deposition, optical photolithography, oxidation and doping, wet processing, plasma etching, and other processes
 - Characterization equipment including SEM and AFM available

Stanford Photonics Research Center *incorporating the Center for Novel Optoelectronic Materials (CNOM)*



A \$60-million dollar 120,000-square-foot photonics laboratory with 20 faculty, 120 doctoral, and 50 postdoctoral researchers, completed in 2004.

Current Research:

Diode Pumped Solid State Lasers

Diode pumped lasers for gravitational wave receivers
Diode pumped Laser Amplifier Studies
Quantum Noise of solid state laser amplifiers
Adaptive Optics for Laser Amplifier beam control
Thermal Modeling of Diode Pumped Nd:YAG lasers

Laser Interferometry for Gravity Wave detection

Sagnac Interferometer for Gravitational Wave Detection
Laser Interferometer Isolation and Control Studies
Interferometry for Gravitational Wave Detection
Time and Frequency response characteristics of Fabry Perot Int.
GALILEO research program: gravitational wave receivers

Quasiphasematched Nonlinear Devices

Quasi Phasematched LiNbO_3 for SHG of diode lasers, cw OPO studies in LiNbO_3 , and diffusion bonded, GaAs nonlinear materials